Large Nuclear Overhauser Fields Detected in Vertically Coupled Double Quantum Dots

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We report the electrical induction and detection of dynamic nuclear polarization in the spin-blockade regime of double GaAs vertical quantum dots. The nuclear Overhauser field measurement relies on bias voltage control of the interdot spin exchange coupling and measurement of dc current at variable external magnetic fields. The largest Overhauser field observed was about 4 T, corresponding to a nuclear polarization $\approx 40\%$ for the electronic g factor typical of these devices, $|g^*| \approx 0.25$. A phenomenological model is proposed to explain these observations.

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Abundant nuclear spins present in semiconductor nanostructures couple collectively to the spins of confined electrons through the contact hyperfine interaction. In situations of mesoscopic confinement, an electron spin typically interacts with $N \sim 10^5 - 10^6$ nuclear spins. Gallium arsenide (GaAs) consists of ⁷¹Ga, ⁶⁹Ga and ⁷⁵As isotopes, each bearing nuclear spin I = 3/2. Nuclear Overhauser fields due to dynamic nuclear polarization (DNP) can produce measurable effects on spin-dependent electron transport, for example, in the spin-blockade (SB) regime of double quantum dots [1,2] or in quantum well structures in the quantum Hall regime at special Landau level filling factors [3]. In the absence of near-perfect nuclear polarization, field fluctuations of order A/\sqrt{N} ($A \approx 90 \ \mu eV$ is the hyperfine coupling constant in GaAs [4]) are the main source of dephasing for electron spin qubits in GaAs quantum dots [5-8]. Dynamically polarizing the nuclear spin system either optically [9,10] or electrically [11] has been proposed as one way to mitigate this effect [5,12]. Polarized ensembles of nuclear spins could also serve as a quantum memory, utilizing long spin coherence times [13,14]. Electrical control of the nuclear polarization in such devices is therefore highly desirable.

Earlier experiments on transport in the SB regime of vertical coupled dots showed magnetic-field dependent current features such as a hysteretic current step and slow oscillations [1]. These features were identified with the presence of DNP and complex feedback between the electronic and nuclear spin systems. It has been proposed that DNP occurs in this system near a level degeneracy at which a blockaded spin-triplet state with one electron in each dot (e.g., $|T_-\rangle = |\downarrow\downarrow\rangle$) is mixed with the singlet state $|S\rangle = \frac{1}{\sqrt{2}}(|\uparrow\downarrow\rangle - |\downarrow\uparrow\rangle)$ via the flip-flop terms of the hyperfine interaction, allowing transport through the dots [1,15]. A mutual electron (nuclear) spin flip (flop) occurs to conserve angular momentum, and energy conservation is generally provided by inelastic processes [16]. Since the hyperfine mixing is only efficient for one of the triplet states, the

nuclear spins are pumped toward a polarized state. Cotunneling processes due to strong coupling with the leads yield finite lifetimes for the triplet states not efficiently mixed by the hyperfine interactions. The accumulated nuclear polarization causes an Overhauser field (henceforth defined as the average Overhauser field of the two dots) that shifts the energy levels of the $|T_{\pm}\rangle$ triplet states. In this Letter, we determine the Overhauser field based on dc current measurement and voltage control of the interdot exchange coupling, with results that imply large nuclear polarizations. The degree of nuclear polarization can be controlled by varying the external magnetic field. Finally, a phenomenological model is proposed to provide a qualitative understanding of these results.

Experiments were performed on a 0.4 μ m diameter vertical double-dot structure [15,17,18] with 10 nm GaAs quantum wells, 7 nm Al_{0.3}Ga_{0.7}As outer tunnel barriers, and 6.5 nm center barrier, at a sample temperature 1.7 K. Gate voltage was adjusted to give a clear SB region in the current-voltage characteristic [1,15]. Measurements consisted of recording dc current as a function of source-drain voltage at variable external magnetic fields. The external field was applied in the plane of the quantum wells so that it had negligible effect on the dot electronic wave functions.

Figure 1 shows a schematic energy level diagram for the two-electron states relevant to these experiments. The horizontal axis is the degree of energy detuning ϵ between the two dots, which is varied experimentally by changing the source-drain voltage $V_{\rm sd}$. We define detuning such that an interdot tunneling resonance between the (1,1) and (0,2) charge configurations of the spin singlet state is centered at $\epsilon = 0$. In our device, $\epsilon \approx 0.27V_{\rm sd} + \epsilon_0$, with $\epsilon = 0$ located slightly to positive $V_{\rm sd}$. The energy eigenvalues plotted in Fig. 1 were calculated by taking into account intra- and interdot Coulomb energies, the interdot tunnel coupling *t*, and $\epsilon(V_{\rm sd})$ [15]. At large negative detuning, the (0,2) singlet is high in energy, and Coulomb blockade

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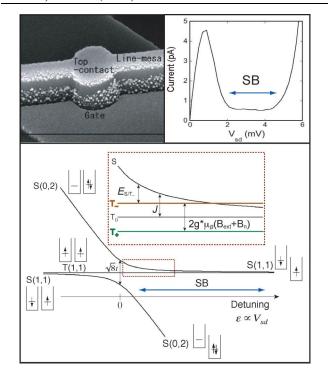


FIG. 1 (color online). (upper, left) Scanning electron microscope image of a device nominally identical to the one investigated here. The double quantum dot is located in the pillar structure just below the surface of the gate metal. (upper, right) Spin-blockade region (labeled "SB") in the I-V characteristic at zero external magnetic field ($B_{\text{ext}} = 0$). (lower) Schematic energy diagram of the two-electron eigenstate energies as a function of the relative detuning ϵ of the two dots. The main figure shows the anticrossing (resonance) of the (1,1) and (0,2)charge configurations of the spin singlet state, which are coupled with the interdot tunneling parameter t. The (1,1) triplet state energy is independent of detuning. The expanded view shows the region just to the right of the resonance which is the focus of these experiments. The Zeeman splitting of the T_+/T_- states depends both on the external field B_{ext} and the average nuclear Overhauser field B_n . The spin exchange energy is J and the level separation between $|T_{-}\rangle$ and $|S\rangle$ is denoted by $E_{S/T}$.

occurs. Spin blockade is mainly observed at positive detuning. The spin exchange coupling *J* has a maximum value $\sqrt{2}t$. The expanded region in Fig. 1 shows that application of an external magnetic field B_{ext} splits off the $|T_{\pm}\rangle$ states due to the Zeeman interaction. Nuclear polarization arising in the two dots from the hyperfine mixing of $|T_{-}\rangle \rightarrow |S\rangle$ is antiparallel to B_{ext} , but causes an Overhauser field $B_n || B_{\text{ext}} \operatorname{since} \operatorname{sgn}(gA) = -1$, where *g* is electronic *g* factor. The energy difference $E_{S/T_{-}}$ between $|T_{-}\rangle$ and $|S\rangle$ plays a leading role in the DNP process under study. By varying detuning using V_{sd} , we can manipulate the field $B_{\text{ext}} + B_n$ for which $E_{S/T_{-}} = 0$.

Figure 2(a) shows that a current step of magnitude ~ 0.5 pA is observed when $V_{\rm sd}$ is swept towards larger detuning at fixed external field $B_{\rm ext}$ [15]. The characteristic step is very similar to that observed in Ref. [1] while

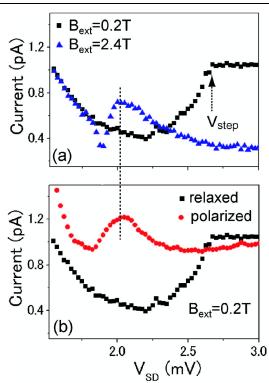


FIG. 2 (color online). (a) Expanded view of the spin-blockade region, showing current steps obtained by sweeping V_{sd} (left to right) at $B_{ext} = 0.2$ T and $B_{ext} = 2.4$ T. V_{step} indicates the position of the 0.2 T step. A dot-lead resonance peak near $V_{sd} = 1$ mV (see upper right of Fig. 1) gives rise to the background slope for $V_{sd} < 2.0$ mV. (b) "Relaxed" trace is the $B_{ext} = 0.2$ T trace in *a*; "Polarized" trace was obtained at the same external field after pumping the nuclear polarization at $V_{sd} = 3.0$ mV for 30 s.

sweeping B_{ext} at fixed V_{sd} . This step appears to indicate the level crossing $E_{S/T_{-}} = 0$, and it shifts toward smaller $V_{\rm sd}$ (i.e., smaller detuning) with increasing $B_{\rm ext}$ as expected from Fig. 1. We assign the step position V_{step} to the edge of the upper current level, as shown in Fig. 2(a). No step was detected for $B_{\text{ext}} < 0.1 \text{ T}$ in the present device. Traces were obtained at a sweep rate of 0.15 mV s^{-1} . Figure 2(b) shows that V_{step} is also shifted in the presence of a nuclear Overhauser field. To obtain the trace labeled "polarized," we first pumped the nuclear polarization by fixing $V_{\rm sd} > V_{\rm step}$ for the $V_{\rm step}$ observed in the absence of an Overhauser field (trace labeled "relaxed"). After pumping about 30 s, V_{sd} is rapidly returned to $V_0 = 1$ mV and subsequently swept up again to obtain the second trace. Both traces in Fig. 2(b) are taken at the same value of $B_{\rm ext} = 0.2$ T. The position of the shifted current step is nearly identical to the V_{step} obtained at larger $B_{\text{ext}} = 2.4 \text{ T}$ in Fig. 2(a). From these experiments, we conclude that the Overhauser field B_n present in Fig. 2(b) can be estimated as the difference in external fields applied in Fig. 2(a). All such measurements were preceded by suitably long wait times at $V_{\rm sd} = 0$ to allow for relaxation of residual nuclear

polarization from previous traces. Relaxation of nuclear polarization occurring during the readout sweep is discussed below.

The experiments of Fig. 2 were repeated over a range of B_{ext} values, and the results are summarized in Fig. 3. The points in Fig. 3(a) are the measured values of V_{step} versus B_{ext} for the two measurement sequences described above. The estimated Overhauser fields B_n are the differences between the two curves along the B_{ext} axis. The B_n estimates plotted in Fig. 3(b) were obtained by subtracting the points from the "polarized" sequence from an empirical curve fit to the "relaxed" data points. Note that Fig. 3(b) differentiates between B_n values that can be determined directly from measured data points and those determined from the extrapolated portion of the fitted curve at $B_{\text{ext}} >$ 3.6 T in Fig. 3(a). The behavior observed in this latter range is most likely due to the polarization dynamics occurring near the zero detuning point, i.e., where the states $|T_{-}\rangle$ and $|T_{+}\rangle$ can both be nearly degenerate with the upper and lower singlet branches, respectively. B_n reaches its maximum value ≈ 4 T near $B_{\text{ext}} = 0.65$ T.

Relaxation measurements of the quantity $B_n(\tau)$ were obtained by inserting a variable delay τ at $V_{sd} = 0$ after pumping in the "polarized" measurement sequence. A biexponential decay was observed with decay times of 13 ± 3 and 68 ± 10 seconds at $B_{ext} = 0.2$ T. Intrinsic nuclear spin relaxation is expected to be much slower than the rate of polarization loss due to spin diffusion, and we estimate the latter to yield a ~10–20 s time scale for diffusion in the vertical direction. Given the finite duration of the readout voltage sweep, the actual Overhauser fields should be slightly larger than measured, by about 20% for the largest fields, if a correction is made based on the measured relaxation. Using the expression for B_n in GaAs obtained in Ref. [4], inserting $|g^*| = 0.25$ from measurement of a

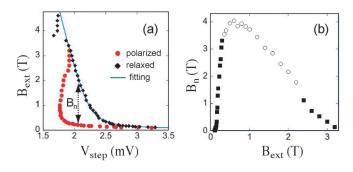


FIG. 3 (color online). (a) Measured current step positions V_{step} versus external field, for the two measurement sequences described in the text. The data from the relaxed sequence have been numerically fit to an empirical function. The differences along the vertical axis between the polarized data points and this curve yield estimates of the Overhauser fields B_n , which are plotted in b. (b) The values that rely on the extrapolated portion of the fitting curve in a (e.g., for $B_{\text{ext}} > 3.6$ T) are shown as open circles, and those that can be determined directly from the data points are shown as filled squares. Experimental uncertainty is indicated by the size of the symbols.

nominally identical device [19], and assuming equal isotopic polarizations, we obtain an average nuclear polarization $P \approx B_n/(9.32T)$. The data therefore suggest a maximum polarization lying within the range 0.38–0.52.

To model this behavior, we consider the rate for an electron to escape the spin blockade due to hyperfineinduced singlet-triplet mixing. The two-electron spin Hamiltonian $\mathcal{H} = \mathcal{H}_0 + \mathcal{H}'$ consists of the Zeeman and exchange terms $(\hat{\mathcal{H}}_0)$ and perturbing hyperfine coupling terms (\mathcal{H}') . The triplet and singlet eigenstates of \mathcal{H}_0 are mixed only by the hyperfine terms involving differences of the effective nuclear fields between the two dots. We define the difference fields $\tilde{h}_{\xi} = \frac{A}{2} \langle I_{\xi}^1 \rangle$ $\langle I_{\xi}^2 \rangle$), where $\langle I_{\xi}^1 \rangle$ is the average ξ component of spin per nucleus in dot 1 (here we assume uniform hyperfine couplings for simplicity). Statistical fluctuations give rise to fields $|\tilde{h}_{\xi}| \sim A/\sqrt{N}$ where N is the average number of nuclear spins. The rate of nuclear spin $\Delta m_z = -1$ transitions $(\uparrow \rightarrow \downarrow)$ is determined by the rate of escape from $|T_{-}\rangle$ via hyperfine mixing with $|S(1, 1)\rangle$, and subsequent tunneling to the (0,2) and (0,1) charge configurations. For $E_{S/T_{-}} \gg \tilde{h}_{x,y}$, this can be treated by second-order perturbation theory [16] and the rate written as $W_{\uparrow \rightarrow \downarrow} =$ $\rho_{T'_{-}}|\langle S(1,1)||T'_{-}\rangle|^2\Gamma_{S(1,1)\to(0,1)}$, where $\rho_{T'_{-}}$ is the steadystate occupation probability for the perturbed eigenstate $|T'_{-}\rangle$ and $\Gamma_{S(1,1)\to(0,1)}$ is the rate of escape from $|S(1,1)\rangle$ to (0,1) via (0,2). In general, $\Gamma_{S(1,1)\to(0,1)}$ can reflect both elastic and inelastic processes, and therefore depends on tunnel couplings, phonon scattering rates, and cotunneling processes; here, it is only considered phenomenologically as a parameter. Using first-order perturbation theory, we can write $W_{\uparrow \rightarrow \downarrow} \approx \alpha (\frac{A/\sqrt{N}}{E_{S/T_{-}}})^2$, where $\alpha = \rho_{T'_{-}} \Gamma_{S(1,1) \rightarrow (0,1)}$. The rate of change of nuclear polarization in the *i*th dot can be expressed:

$$\frac{d\langle I_Z^j \rangle}{dt} = \frac{W_{\downarrow \to \uparrow}(1 - p_{3/2}^j) - W_{\uparrow \to \downarrow}(1 - p_{-3/2}^j)}{2N_j} - \frac{|\langle I_Z^j \rangle|}{T_1}$$
(1)

where $p_{\pm 3/2}$ are the normalized populations of the $m_z =$ $\pm 3/2$ sublevels and we assume an equal probability 1/2for a nuclear spin transition to occur in dot 1 or dot 2. T_1 is the phenomenological relaxation rate of nuclear polarization (including spin diffusion out of the dots), and N_i is the number of nuclear spins in the *j*th dot. As V_{sd} is swept up, $E_{S/T_{-}}$ decreases (see Fig. 1) and $W_{\uparrow \rightarrow \downarrow}$ increases; a small nuclear polarization begins to accumulate. Since $E_{S/T_{-}} =$ $J - |g^*| \mu_B B_{\text{ext}} + A \langle I_Z \rangle$, E_{S/T_-} is further decreased by the nuclear Overhauser field $A\langle I_Z \rangle = -|g^*|\mu_B B_n < 0$ and positive feedback occurs. Once this occurs, the system is forced to pass through the degeneracy $E_{S/T_{-}} = 0$ where the pumping rate is maximum and is limited by the (nonnuclear spin flip) escape rates of the $|T_+\rangle$ and $|T_0\rangle$ states [20]. This is illustrated schematically in Fig. 4. A steady state is then reached in the regime of $E_{S/T_{-}} < 0$, at which

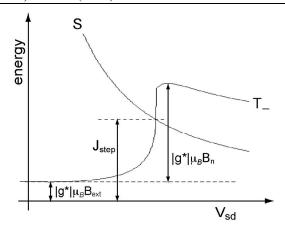


FIG. 4. A schematic diagram showing the dynamics of the $|T_{-}\rangle$ energy level as the source-drain voltage V_{sd} is swept from left to right and dynamic nuclear polarization occurs near the $E_{S/T_{-}} = 0$ degeneracy. J_{step} indicates the value of J at the crossing point, which is approximately the position (in V_{sd}) of the observed current step.

the steady-state nuclear polarization can be determined by setting $\frac{d\langle I_Z \rangle_{ss}}{dt} = 0$ and solving self-consistently for $\langle I_Z \rangle_{ss}$. A straightforward analysis shows that $\alpha \sim 10^8$ Hz is necessary for steady-state polarizations ~ 0.1 , using reasonable parameters (e.g., $T_1 \sim 30$ s, $N \sim 5 \times 10^5$). Such a fast rate for α (on the order of the dot-lead tunneling rate) is possible near the singlet-singlet resonance where $|S(1, 1)\rangle$ and $|S(0, 2)\rangle$ are hybridized by a relatively large interdot tunnel coupling $\sim 50 \ \mu eV$. A detailed modeling of the double-dot transport and polarization dynamics will be required to fully understand the dependence of B_n on B_{ext} , and also the origin of the current step [21]. However, we do expect B_n to fall off as B_{ext} is increased (as in Fig. 3(b) for $B_{ext} > 1$ T) due to increasing pumping of the opposite transition $W_{l\to 1}$ via the state $|T_+\rangle$ mixing with the lower singlet branch.

In conclusion, we have shown that surprisingly large nuclear polarizations can be electrically induced and detected in the present GaAs double-dot system. One drawback is the detection scheme: the magnitude of polarization that can be detected is limited by the range of B_{ext} over which we can observe a clear current step, and additionally by the fact that dot-lead tunneling rates will be reduced at large B_{ext} due to a momentum mismatch between dot and lead states [22]. Indeed, it is likely that significantly larger polarization was actually achieved in our experiments than was detected, since the current step observed in the readout V_{sd} sweep suggests a secondary polarization boost. Another detection method, such as electron spin resonance, could be used to extend these measurements in similar devices.

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